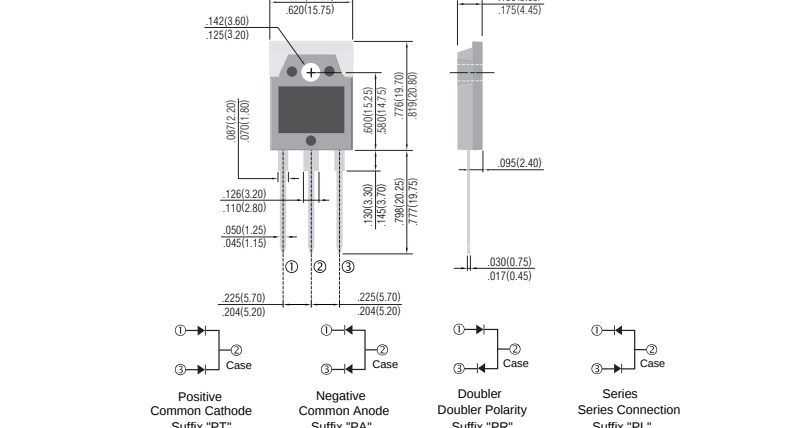


Pb Free Plating Product

MUR6020PL thru MUR60120PL



60.0 Ampere Heatsink Dual Series Connection Ultra Fast Recovery Rectifiers

Features	TO-3P(TO-3PN-SQ) Unit:inch(mm)
※ ThinkSemi latest&matured process FRD ※ Low forward voltage drop ※ High current capability ※ Low reverse leakage current ※ High surge current capability	
Application	
※ Automotive Inverters and Solar Inverters ※ Car Audio Amplifiers and Sound Device Systems ※ Plating Power Supply, Motor Control, UPS and SMPS etc.	
Mechanical Data	
※ Case: Heatsink open metal TO-3P(TO-3PN/TO-3PB) package ※ Epoxy: UL 94V-0 rate flame retardant ※ Terminals: Solderable per MIL-STD-202 method 208 ※ Polarity: As marked on diode body ※ Mounting position: Any ※ Weight: 6.5 gram approximately	

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	MUR6020PL	MUR6030PL MUR6040PL	MUR6060PL	MUR6080PL	MUR60100PL	MUR60120PL	UNIT	
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	800	1000	1200	V	
Maximum RMS Voltage	VRMS	140	280	420	560	700	840	V	
Maximum DC Blocking Voltage	VDC	200	400	600	800	1000	1200	V	
Maximum Average Forward Rectified Current TC=125°C (Total Device 2x30.0A=60.0A)	IF(AV)	60.0						A	
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)(Per Diode/Per Leg)	IFSM	600						A	
Maximum Instantaneous Forward Voltage @30.0A(Per Diode/Per Leg)	VF (Typical)	0.90-1.10	1.10-1.40	1.40-1.80	1.40-1.80			V	
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	5.0 500				µA µA			
Maximum Reverse Recovery Time (Note1)	Trr	35-50			50-75				nS
Typical Junction Capacitance (Note 2)	CJ	300				pF			
Typical Thermal Resistance (Note 3)	RθJC	0.75						°C/W	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 to +175						°C	

Note:(1)Reverse recovery test conditions IF = 0.5A, IR = 1.0A, Irr = 0.25A.

Note:(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

Note:(3)Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

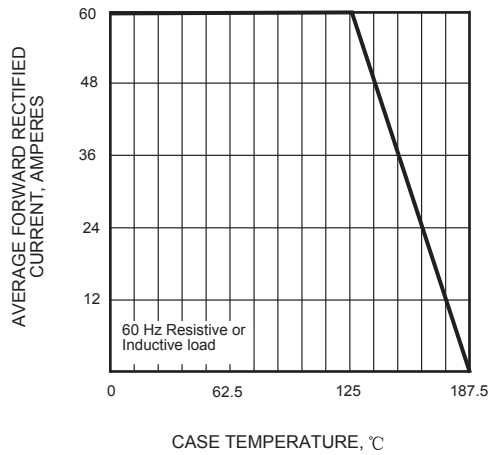


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

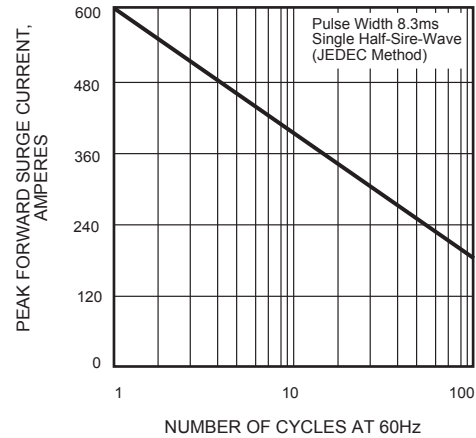


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

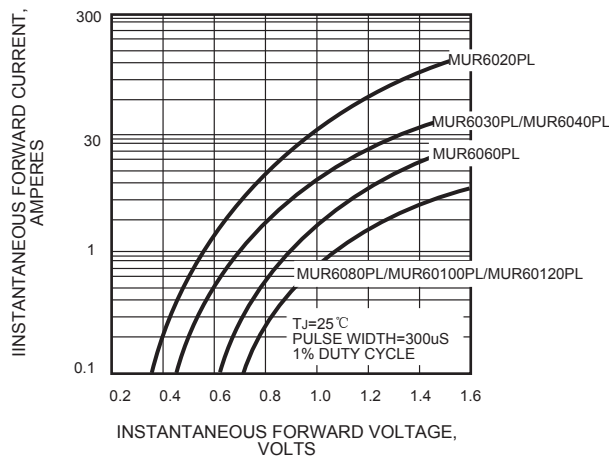


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

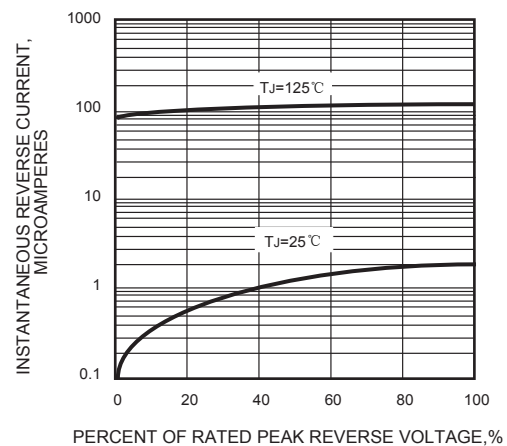


FIG.5 - TYPICAL JUNCTION CAPACITANCE

